## Ho:YLF

Ho ions are used as active ions, the pumping wavelength is  $1.9 \mu m$ , and the output wavelength is  $2.05 \mu m$  linearly polarized laser, which can well pump ZGP to output 3-5  $\mu m$  mid-wave infrared laser. Selecting the appropriate doping concentration and crystal size can output a higher power  $2.05 \mu m$  laser, which is an important pump source laser crystal for mid-wave infrared lasers.

## Main features:

Linearly polarized laser output The thermal effect of laser operation is small Suitable for 1.9µm laser pumping Material properties:

| Melting point                    | 825°C                                   |
|----------------------------------|-----------------------------------------|
| Moh's hardness                   | 4-5                                     |
| Density                          | 3.95g/ <sup>cm3</sup>                   |
| Thermal conductivity             | 0.06W/cm/K                              |
| Young's modulus                  | 7.5×1011dynes cm <sup>-2</sup>          |
| Tensile strength                 | 3.3×108dynes cm <sup>-2</sup>           |
| Coefficient of thermal expansion | [100] Direction: 13×10 <sup>-6</sup> /K |
|                                  | [001] Direction: 8×10 <sup>-6</sup> /K  |

**Product parameters:** 

| Doping concentration                           | 0~3at% can be customized according to customer requirements |
|------------------------------------------------|-------------------------------------------------------------|
| Orientation                                    | [100] or [001], deviation within 5°                         |
| Wavefront distortion                           | ≤0.25λ/25mm @632.8nm                                        |
| Crystal rod size                               | Diameter: 3~9.5mm, Length: 5~120mm can be customized        |
| Dimensional tolerance                          | Diameter: +0.00/-0.05mm, Length: ± 0.5mm                    |
| Cylindrical processing                         | Grinding or Polishing                                       |
| Parallelism of end faces                       | ≤10"                                                        |
| Perpendicularity between end face and rod axis | ≤5′                                                         |
| Flatness of end face                           | ≤λ/10@632.8nm                                               |
| Surface Quality                                | 10-5 (MIL-O-13830A)                                         |
| Chamfer                                        | 0.15±0.05mm                                                 |
| AR Coating Reflectance                         | ≤0.25%                                                      |